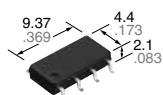
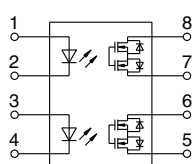


**Normally closed
SOP8-pin type
of 400V load voltage**

**PhotoMOS®
GU SOP 2 Form B
(AQW414S)**



mm inch



RoHS compliant

FEATURES

1. 2 channels in miniature SOP8-pin design

The device comes in a super-miniature SO package measuring —approx. 38% of the volume and 66% of the footprint size of DIP8-pin type.

2. Controls low-level analog signals

PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

3. I/O isolation voltage of 1,500Vrms

TYPICAL APPLICATIONS

- Power supply
- Measuring instruments
- Security equipment
- Industrial robots
- Sensing equipment

TYPES

	Output rating*		Package	Part No.			Packing quantity	
	Load voltage	Load current		Through hole terminal	Surface-mount terminal		Tube	Tape and reel
				Tube packing style	Tape and reel packing style			
					Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side		
AC/DC dual use	400 V	80 mA	SOP8-pin	AQW414S	AQW414SX	AQW414SZ	1 tube contains: 50 pcs. 1 batch contains: 1,000 pcs.	1,000 pcs

*Indicate the peak AC and DC values.

Note: The packing style indicator "X" or "Z" are not marked on the device.

RATING

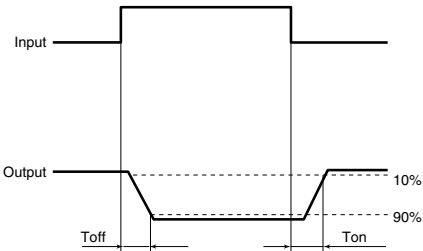
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQW414S	Remarks
Input	LED forward current	I_F	50 mA	
	LED reverse voltage	V_R	5 V	
	Peak forward current	I_{FP}	1 A	$f = 100 \text{ Hz}$, Duty factor = 0.1%
	Power dissipation	P_{in}	75 mW	
Output	Load voltage (peak AC)	V_L	400 V	
	Continuous load current	I_L	0.08 A (0.1 A)	Peak AC, DC (): in case of using only 1 channel
	Peak load current	I_{peak}	0.24 A	100 ms (1 shot), $V_L = \text{DC}$
	Power dissipation	P_{out}	600 mW	
Total power dissipation		P_T	650 mW	
I/O isolation voltage		V_{iso}	1,500 Vrms	
Ambient temperature	Operating	T_{opr}	−40 to +85°C −40 to +185°F	(Non-icing at low temperatures)
	Storage	T_{stag}	−40 to +100°C −40 to +212°F	

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQW414S	Condition
Input	LED operate (OFF) current	Typical	I _{Foff}	0.9 mA	I _L = Max.
		Maximum		3 mA	
	LED reverse (ON) current	Minimum	I _{Fon}	0.4 mA	I _L = Max.
		Typical		0.8 mA	
	LED dropout voltage	Typical	V _F	1.25 V (1.14 V at I _F = 5 mA)	
Maximum		1.5 V			
Output	On resistance	Typical	R _{on}	26 Ω	I _F = 0 mA I _L = Max. Within 1 s
		Maximum		50 Ω	
	Off state leakage current	Maximum	I _{Leak}	1 μA	
Transfer characteristics	Operate (OFF) time*	Typical	T _{off}	0.43 ms	I _F = 0 mA → 5 mA I _L = Max.
		Maximum		1 ms	
	Reverse (ON) time*	Typical	T _{on}	0.3 ms	I _F = 5 mA → 0 mA I _L = Max.
		Maximum		1 ms	
	I/O capacitance	Typical	C _{iso}	0.8 pF	f = 1 MHz V _B = 0 V
		Maximum		1.5 pF	
Initial I/O isolation resistance	Minimum	R _{iso}	1,000 MΩ		500 V DC

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

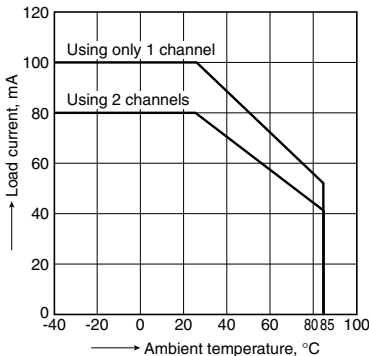
Item		Symbol	Number of used channels	Min.	Max.	Unit
AQW414S	LED current	I _F		5	30	mA
	Load voltage (Peak AC)	V _L		—	320	V
	Continuous load current	I _L	1ch 2ch	—	0.1 0.08	A

■ These products are not designed for automotive use.
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

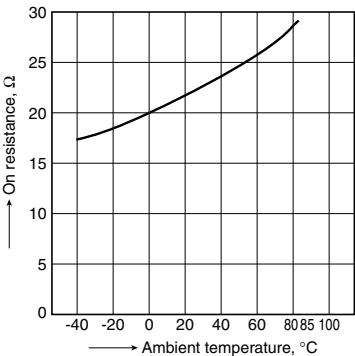
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C
-40 to +185°F



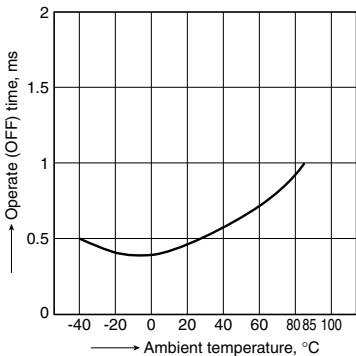
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 0 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



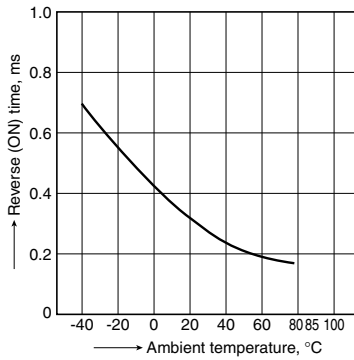
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



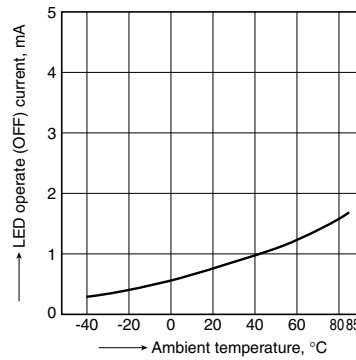
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



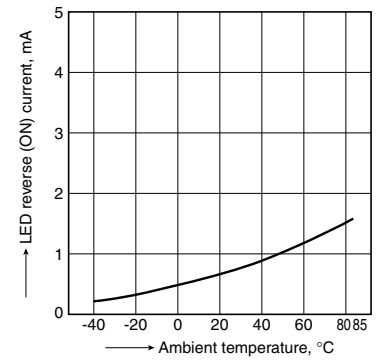
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



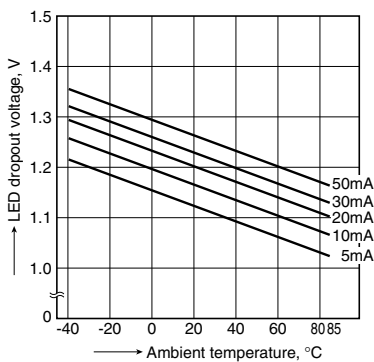
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



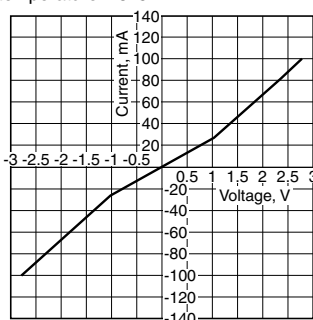
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



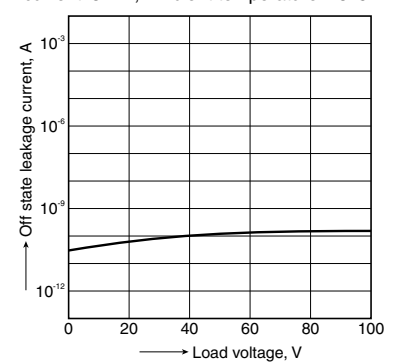
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



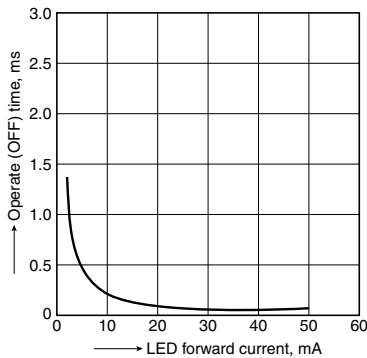
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 5 mA; Ambient temperature: 25°C 77°F



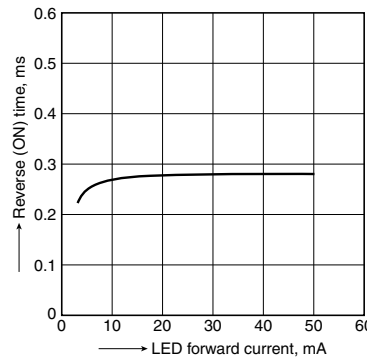
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



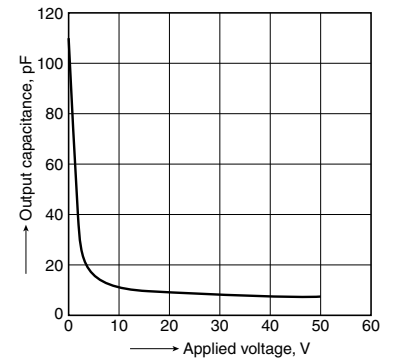
11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 5 mA;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



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*Recognized in Japan, the United States, all member states of European Union and other countries.

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Specifications are subject to change without notice.